



做中国自主知识产权核心处理器
MCU/DSP/CPU芯片级大脑领导者

深圳市航顺芯片技术研发有限公司 航顺浩瀚处理器（广州）有限公司

国家高新技术企业 深圳龙华2017年八大重点签约引进企业
航顺芯片32位通用MCU之M0 M3 M4世界级超低功耗
性能超稳定 开发工具全兼容进口 软硬件全兼容进口

HK431

HK431特殊声明：

- 1：航顺芯片 铁脚封装 精度0.5-0.7% A档（中低端消费类产品建议使用）
- 2：航顺芯片 铁脚封装 精度0.7-1.2% B档（不建议使用）
- 3：航顺大芯片 铁脚封装 精度0.5%（中低端产品建议使用）
- 4：航顺大芯片 铜脚封装 精度0.5%（中高端产品建议使用，抗静电 抗干扰强 精度高）

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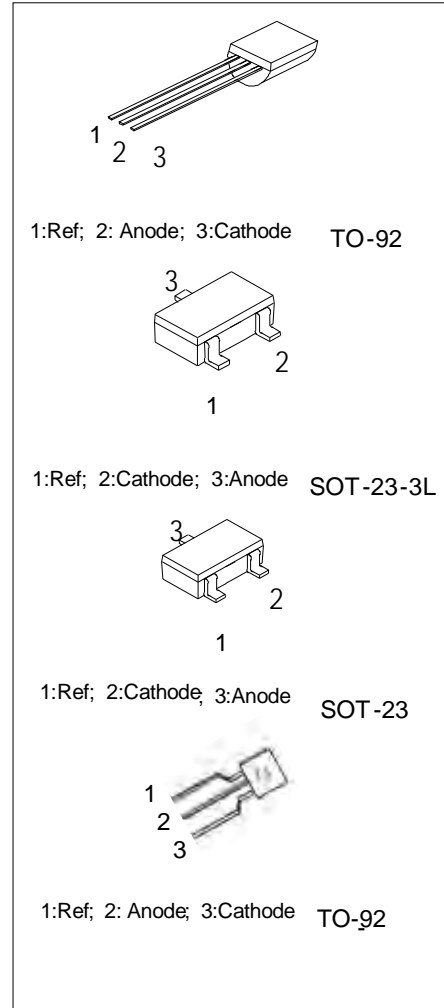
PROGRAMMABLE PRECISION REFERENCE

DESCRIPTION

The HK431 is three-terminal adjustable regulator with a guaranteed thermal stability over applicable temperature ranges. The output Voltage may be set to any value between V_{ref} (approximately 2.5V) and 36 V with two external resistors. These devices provide a very sharp turn-on characteristic, making these devices excellent replacement for zener diodes in many applications.

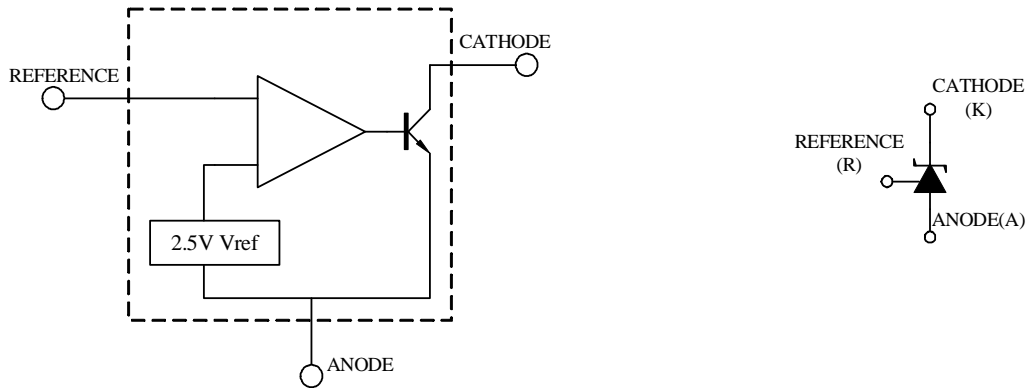
FEATURE

- *Programmable output Voltage to 36V
- *Low dynamic output impedance 0.2Ω
- *Sink current capability of 0.5 to 100mA
- *Equivalent full-range temperature coefficient of 50ppm/°C typical
- *Temperature compensated for operation over full rated operating temperature range
- *Low output noise voltage
- *Fast turn on response



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BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

CHARACTERISTICS	SYMBOL	VALUE	UNITS
Cathode Voltage	V _{KA}	37	V
Cathode Current Range(Continuous)	I _{KA}	-100~+150	mA
Reference Input Current Range	I _{ref}	-0.05~+10	mA
Power Dissipation	P _D	TO-92	770
		SOT-23-3	370
Operating temperature	T _{opr}	-40~+85	°C
Storage temperature Temperature	T _{stg}	-65~+150	°C

RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Min	Typ	Max	Unit
Cathode Voltage	V _{KA}	V _{REF}		36	V
Cathode Current	I _{KA}	0.5		100	mA



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ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

Characteristic		Symbol	Test conditions	MIN	TYP	MAX	UNIT
Reference Input Voltage 1	0.5%	Vref	VKA=VREF, IKA=10mA	2.488	2.50	2.512	V
	1%			2.475	2.50	2.525	
	2%			2.450	2.50	2.550	
Reference Input Voltage 2*	0.5%	Vref	VKA=VREF, IKA=10mA	2.483	2.495	2.507	V
	1%			2.470	2.495	2.520	
	2%			2.445	2.495	2.545	
Deviation of reference Input Voltage Over temperature		ΔV_{ref}	VKA=VREF, IKA=10mA TMIN≤TA≤TMAX		4.5	25	mV
Ratio of Change in Reference Input Voltage to the Change in Cathode Voltage		$\Delta V_{ref}/\Delta V_{KA}$	IKA=10mA	$\Delta V_{KA}=10V \sim V_{REF}$	-1.0	-2.7	mV/V
				$\Delta V_{KA}=36V \sim 10V$	-0.5	-2.0	
Reference Input Current		Iref	IKA=10mA, R1=10kΩ, R2=∞		1	2	μA
Deviation of Reference Input Current Over Full Temperature Range		$\Delta I_{ref}/\Delta T$	IKA=10mA, R1=10kΩ, R2=∞, TA=full Temperature		0.2	0.4	μA
Minimum cathode current for regulation		IKA(min)	VKA=VREF		0.3	0.5	mA
Off-state cathode Current		IKA(OFF)	VKA=36V, VREF=0		0.05	0.5	μA
Dynamic Impedance		ZKA	VKA=VREF, IKA=1 to 100mA f≤1.0kHz		0.15	0.5	Ω

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TEST CIRCUITS

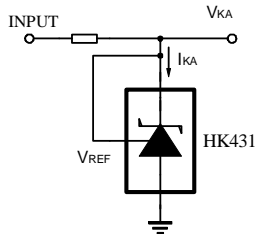


Fig 7 Test Circuit For $V_{KA}=V_{REF}$

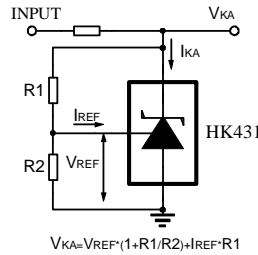


Fig 8 Test Circuit for $V_{KA} \geq V_{REF}$

$$V_{KA} = V_{REF} \cdot (1 + R1/R2) + I_{REF} \cdot R1$$

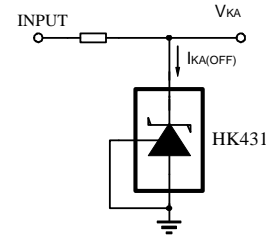


Fig 9 Test Circuit For $I_{KA(OFF)}$

TYPICAL APPLICATION

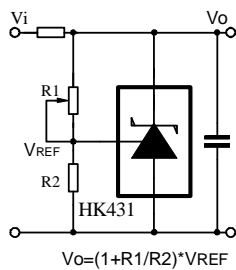


Fig 10 Shutdown Regulator

$$V_o = (1 + R1/R2) \cdot V_{REF}$$

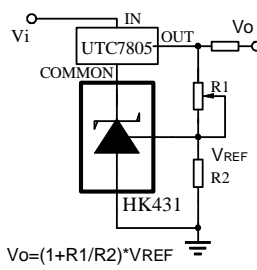


Fig 11 Output Control of a Three-Terminal Fixed Regulator

$$V_o = (1 + R1/R2) \cdot V_{REF}$$

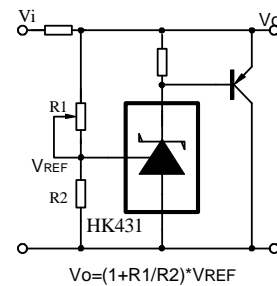


Fig 12 Higher-current Shunt Regulator

$$V_o = (1 + R1/R2) \cdot V_{REF}$$

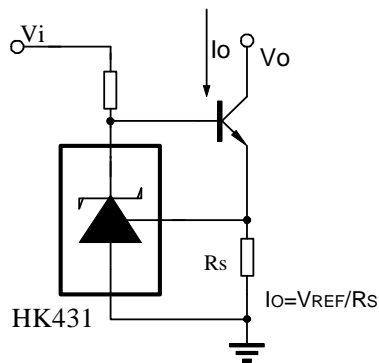


Fig 13 Constant-current Sink

$$I_o = V_{REF}/R_s$$

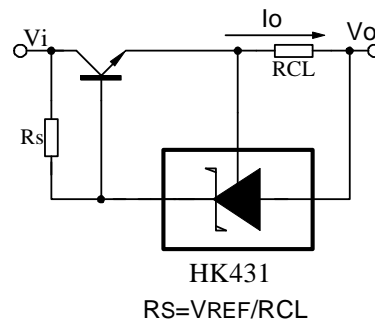


Fig 14 Current Limiting or Current Source

$$R_s = V_{REF}/R_{CL}$$

TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1 Cathode Current Vs Cathode Voltage

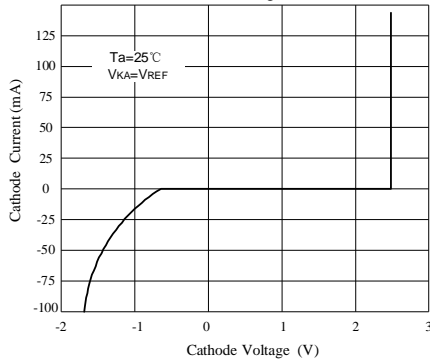


Fig 2 Cathode Current Vs Cathode Voltage

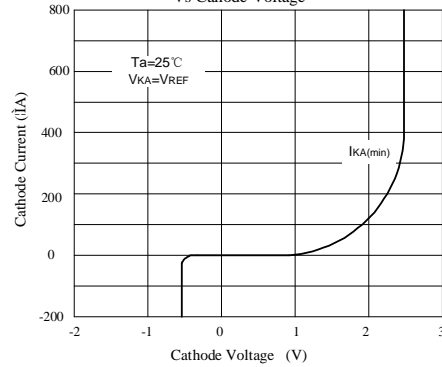


Fig 3 Change in Reference Input Voltage Vs Cathode voltage

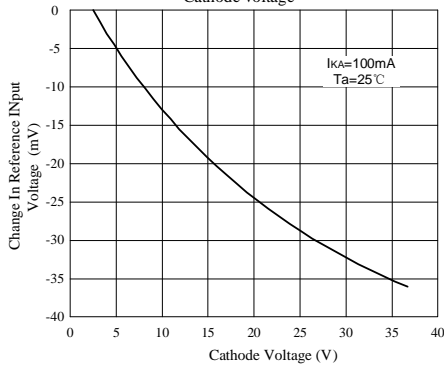


Fig 4 Pulse Response

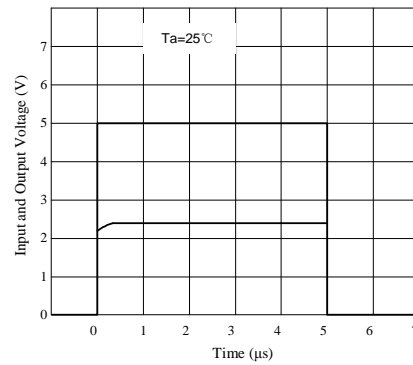


Fig 5 Dynamic Impedance Vs Frequency

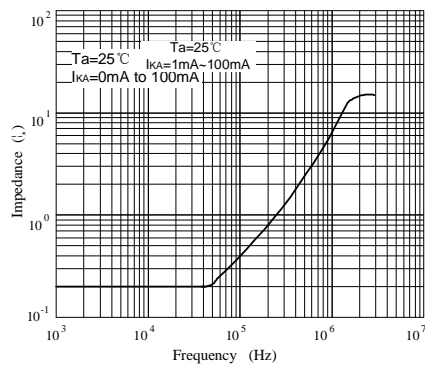


Fig 6 Small Signal Voltage Amplification Vs Frequency

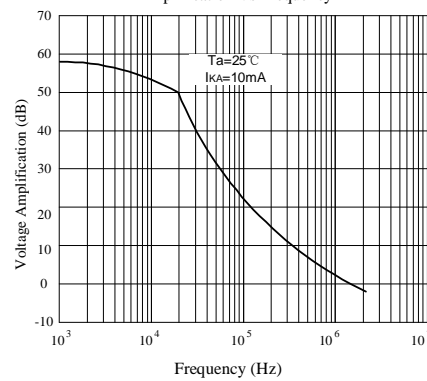
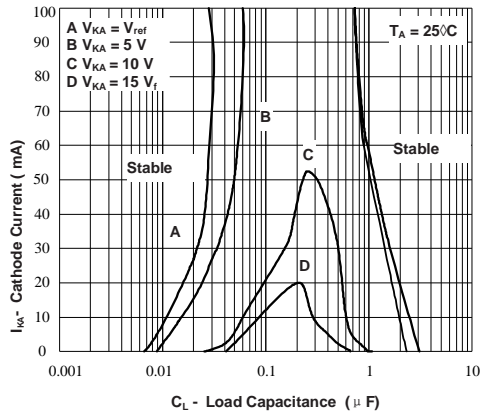
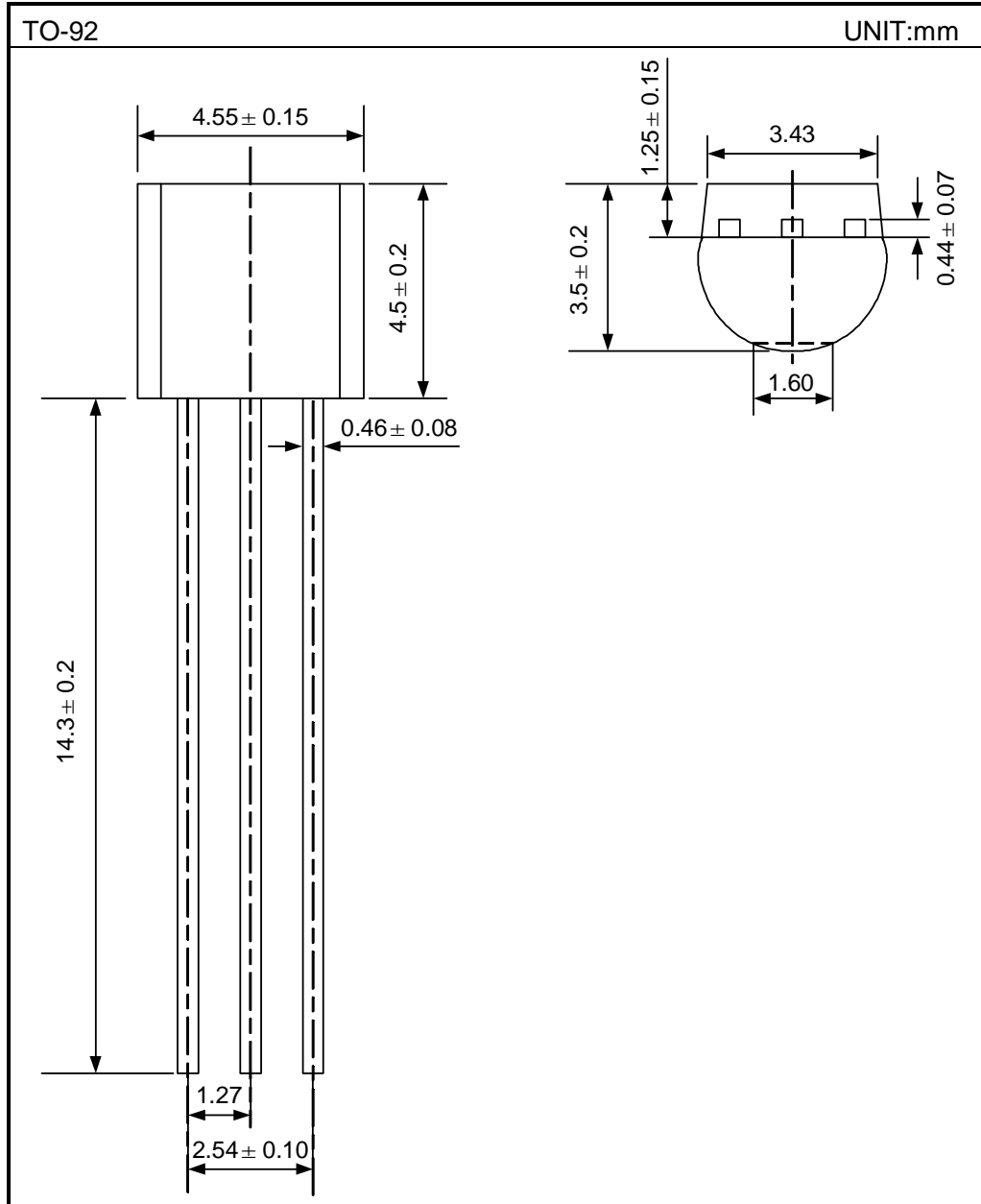


Fig 7 Cathode Current Vs Load Capacitance

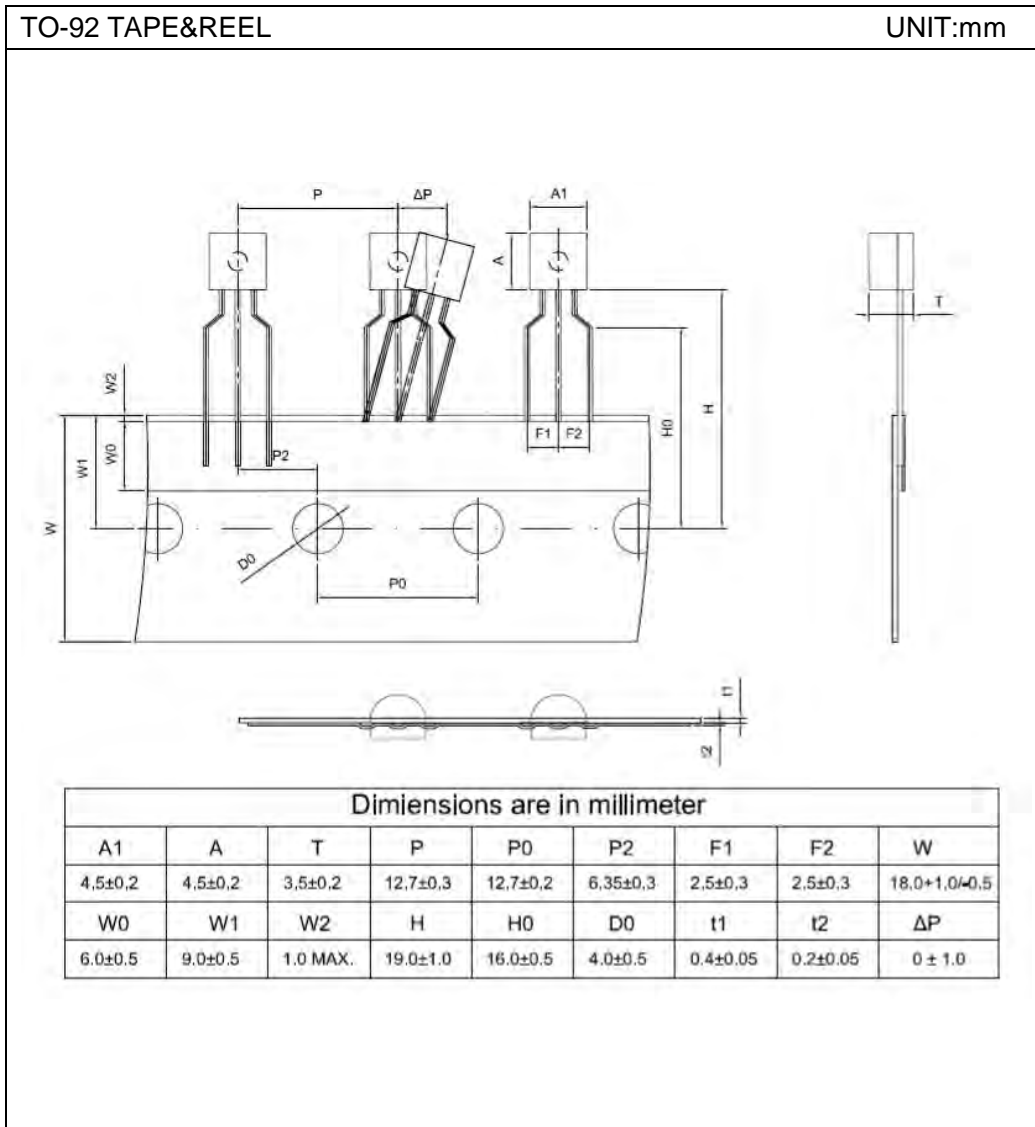


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PACKAGE DIMENSIONS

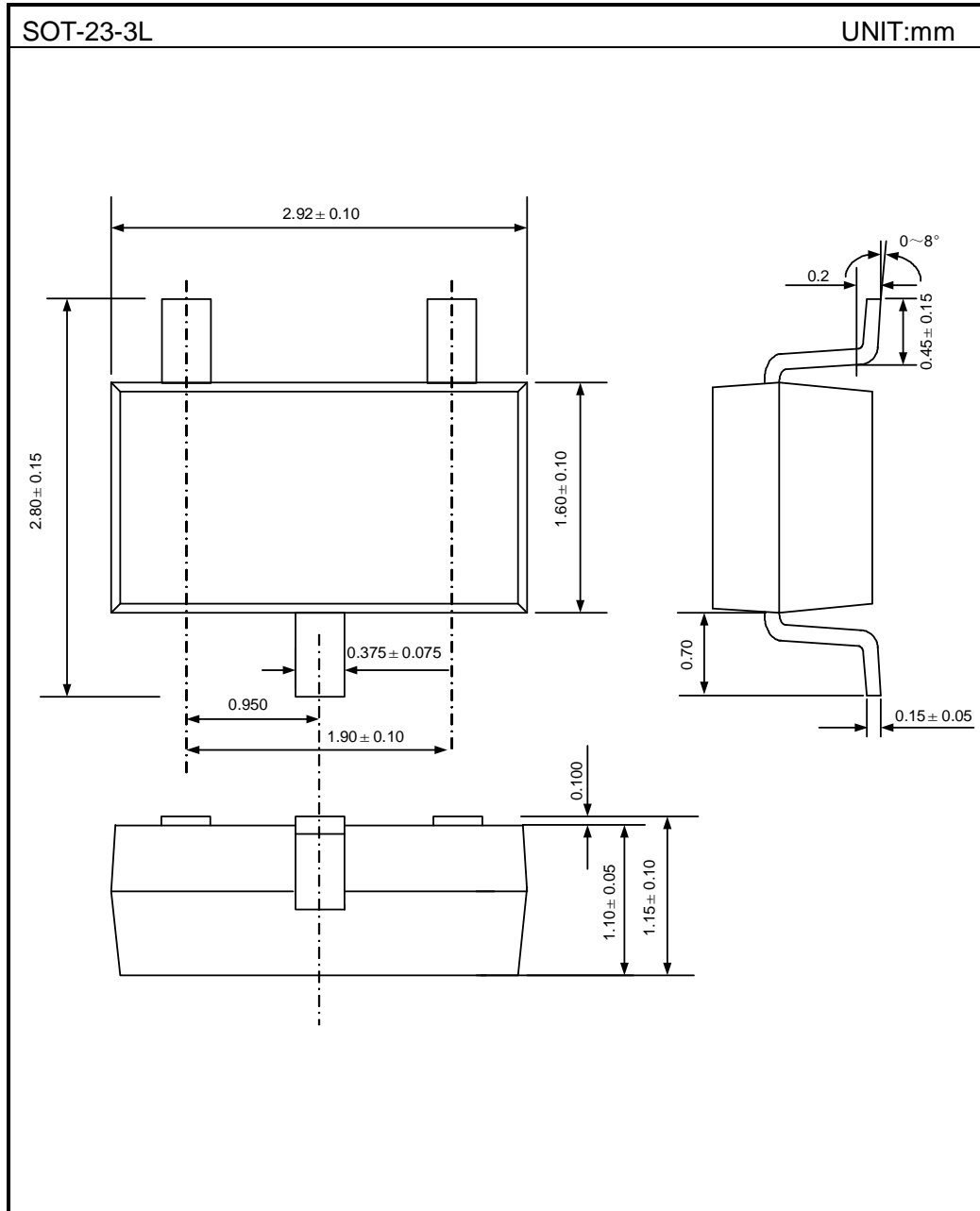


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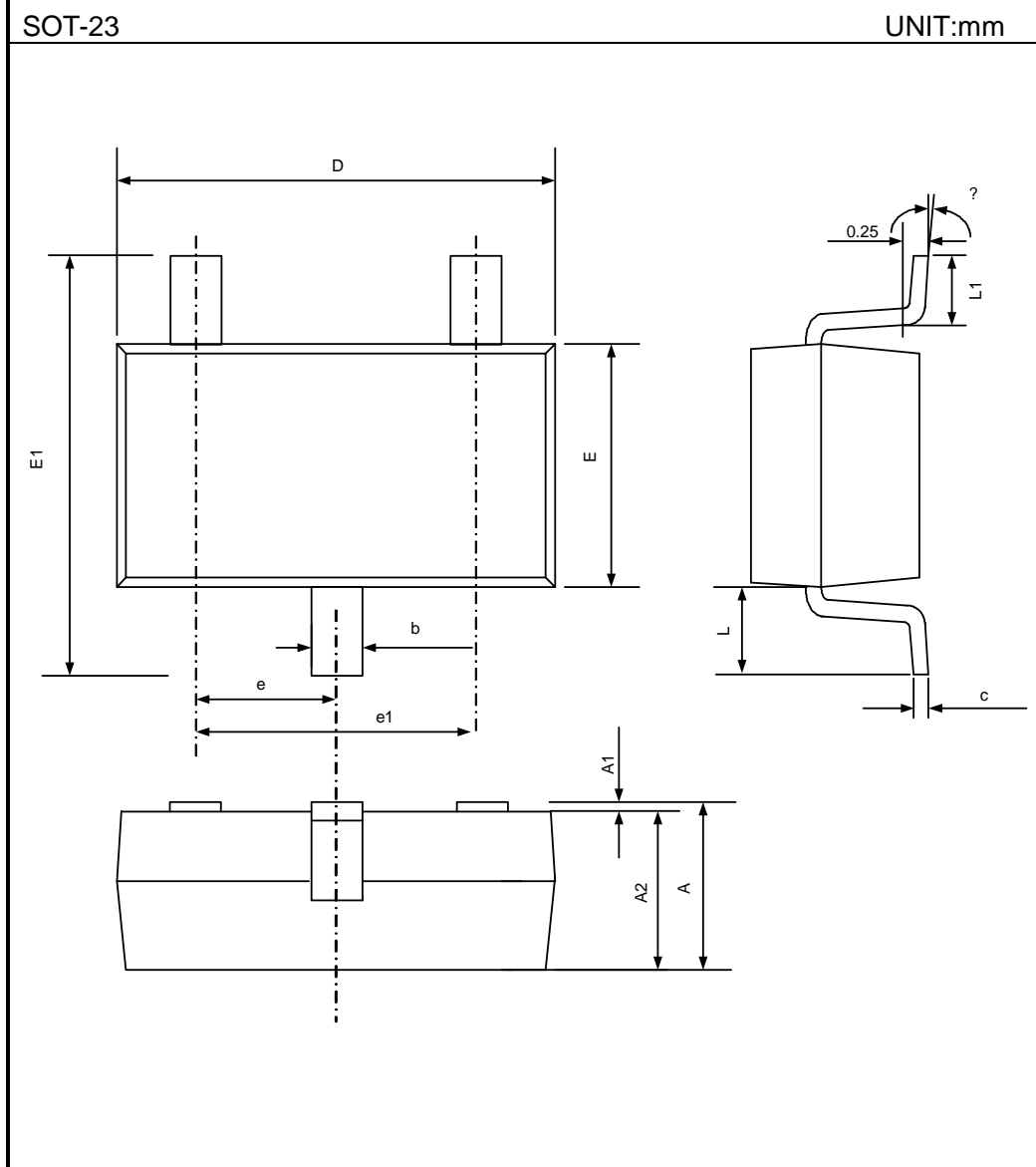
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SOT-23		UNIT:mm		
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.2550	0.089	0.100
e	0.950TYP		0.037TYP	
E1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°



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Attach

Revision History

Data	REV	Description	Page
	1.0	Original	
2006.11.16	1.2	Revise "PACKAGE OUTLINE SOT-23-3"	5
2007.08.01	1.3	Revise Pin	1
2010.05.17	1.4	Increase encapsulation	6
2011.08.31	1.5	Increase TYPICAL PERFORMANCE CHARACTERISTICS Fig.7	5
2012.09.06	1.6	Increase PACKAGE	8